NSN 5961-00-351-8717

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-351-8717 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches Overall Diameter: Between 0.335 inches and 0.370 inches **Internal Configuration:** Unijunction **Mounting Method:** Terminal **Features Provided:** Burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 70.00 milliamperes repetitive peak forward current megahertz and 2.00 microamperes repetitive peak forward current nanoamperes **Power Rating Per Characteristic:** 600.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** rise time 10.0 microseconds; junction pattern arrangement: pn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 10001-2557745 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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